

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and

FAIRCHILD SEMICONDUCTOR

FQPF7N65C N-Channel QFET[®] MOSFET

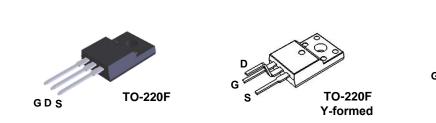
 $650~V, 7~A, 1.4~\Omega$

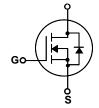
Description

This N-Channel enhancement mode power MOSFET is \bullet 7 A, 650 V, R_{DS(on)} = 1.4 Ω (Max.) @ V_{GS} = 10 V, I_D = 3.5 A produced using Fairchild Semiconductor®'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to . Low Crss (Typ. 12 pF) reduce on-state resistance, and to provide superior • 100% Avalanche Tested switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- Low Gate Charge (Typ. 28 nC)





D

August 2013

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		FQPF7N65C / FQPF7N65CYDTU	Unit	
V _{DSS}	Drain-Source Voltage		650	V	
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		7 *	А	
	- Continuous (T _C = 100°C)		4.2 *	А	
I _{DM}	Drain Current - Pulsed	(Note 1)	28 *	А	
V _{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	212	mJ	
I _{AR}	Avalanche Current	(Note 1)	7	А	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	1.6	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.5	V/ns	
PD	Power Dissipation (T _C = 25°C) - Derate above 25°C		52	W	
			0.42	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
т	Maximum lead temperature for soldering purposes,		300	°C	
ΤL	1/8" from case for 5 seconds	500			

Thermal Characteristics

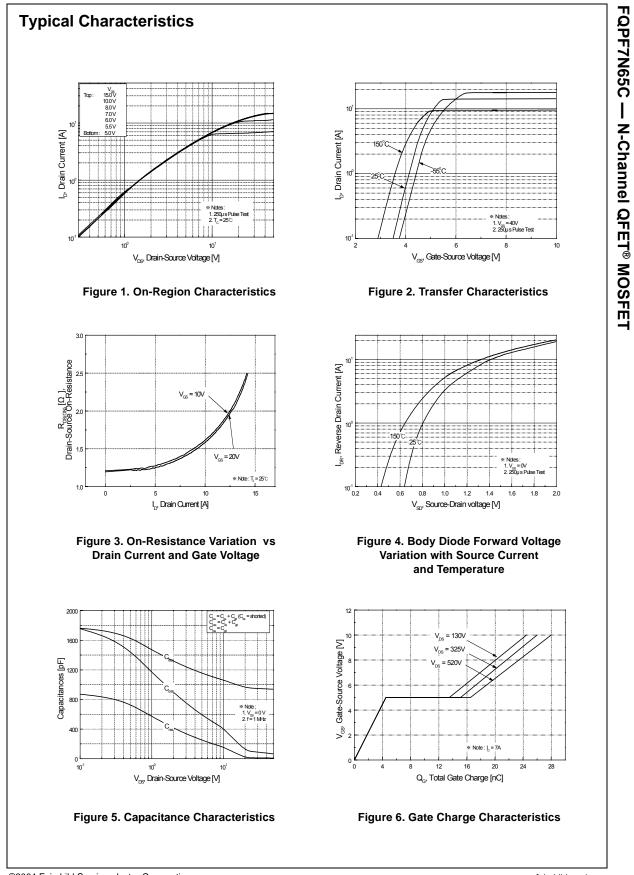
Symbol	Parameter	FQPF7N65C / FQPF7N65CYDTU	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	2.4	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1

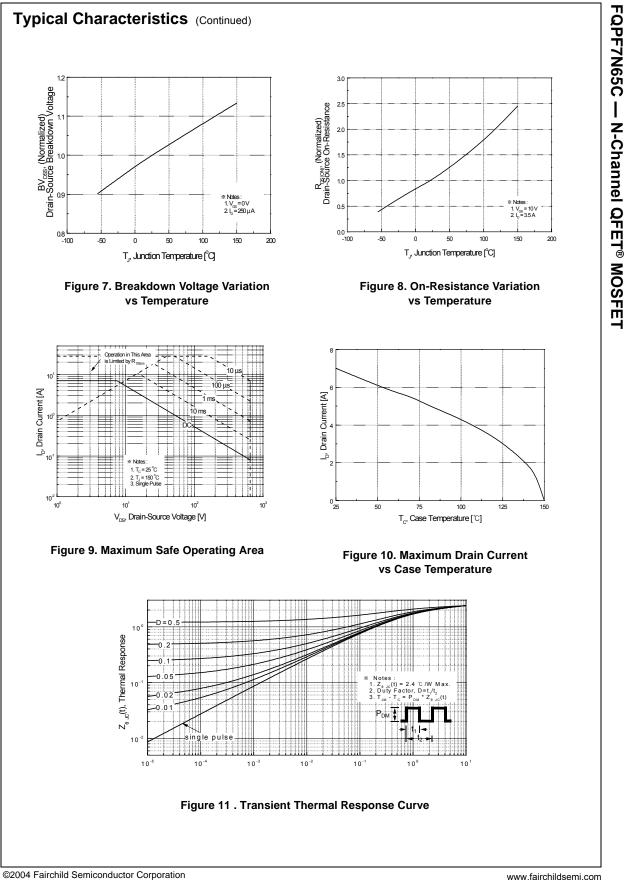
		Device	Package	Reel Size	Tape	Tape Width -		Quantity 50	
		FQPF7N65C	TO-220F	-	-				
		TO-220F (Y-formed)	220F (Y-formed) -		-		50		
Electric	cal Cha	racteristics T	C _C = 25°C unless otherwise noted	d					
Symbol		Parameter	Test Co	onditions	Min	Тур	Max	Unit	
	racterist	ioc							
BV _{DSS}		rce Breakdown Voltage	$V_{aa} = 0 V_{aa} = 1$	250 μΔ	650			V	
ΔBV_{DSS}		n Voltage Temperature		V _{GS} = 0 V, I _D = 250 μA				v	
$/ \Delta T_{J}$	Coefficien	U	I _D = 250 μA, Re	I_D = 250 µA, Referenced to 25°C		0.8		V/°C	
I _{DSS}	Zero Gate Voltage Drain Current		V _{DS} = 650 V, V _C				1	μA	
	Zelo Gale	voltage Drain Current	V _{DS} = 520 V, T _C	₂ = 125°C			10	μA	
I _{GSSF}	Gate-Body	y Leakage Current, For					100	nA	
I _{GSSR}	Gate-Body	y Leakage Current, Rev	verse V_{GS} = -30 V, V_{D}	_S = 0 V			-100	nA	
On Cha	racterist	ics							
V _{GS(th)}	Gate Thre	shold Voltage	$V_{DS} = V_{GS}, I_D =$	250 μΑ	2.0		4.0	V	
R _{DS(on)}	Static Drai On-Resist		V _{GS} = 10 V, I _D =	= 3.5 A		1.2	1.4	Ω	
9 _{FS}	Forward T	ransconductance	V _{DS} = 40 V, I _D =	V _{DS} = 40 V, I _D = 3.5 A		8		S	
Dynam C _{iss} C _{oss}	IC Charac Input Capa Output Ca			V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		955 100	1245 130	pF pF	
C _{rss}		ransfer Capacitance	f = 1.0 MHZ			12	16	pr pF	
Orss	I Ceverse I					12	10	рі	
	-	acteristics					1		
t _{d(on)}	Turn-On E Turn-On F	5	V _{DD} = 325 V, I _D	V _{DD} = 325 V, I _D = 7A,		20	50	ns	
t _r ≁			R _G = 25 Ω			50	110	ns	
t _{d(off)}	Turn-Off D	,		(Note 4		90 55	190	ns	
t _f	Turn-Off F			•		55	120	ns	
Q _g	Total Gate	-	V _{DS} = 520 V, I _D	= 7A,		28	36	nC	
Q _{gs}		rce Charge	V _{GS} = 10 V	(Note 4)	4.5 12		nC nC	
Q _{gd}	Gate-Drai	n Charge		(100 4		12		nc	
			cs and Maximum						
I _S	Maximum	Continuous Drain-Sour	rce Diode Forward Curre	ent			7	Α	
I _{SM}		Pulsed Drain-Source D		-			28	Α	
V _{SD}		rce Diode Forward Volt	0 00 0				1.4	V	
t _{rr}		Recovery Time		V _{GS} = 0 V, I _S = 7A,		400		ns	
Q _{rr}	Reverse F	Recovery Charge	dl _F / dt = 100 A/	μs		3.3		μC	

Downloaded from Arrow.com.

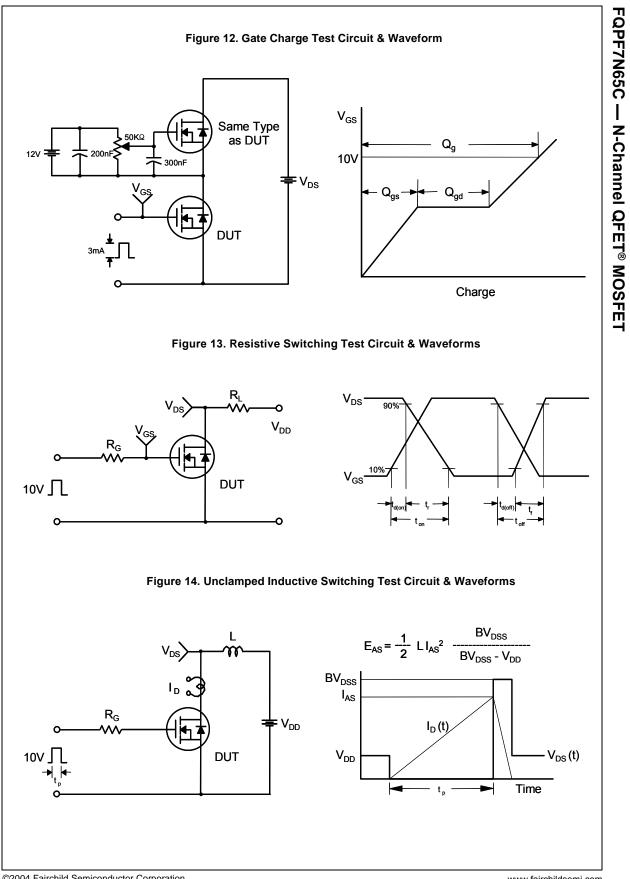
©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1



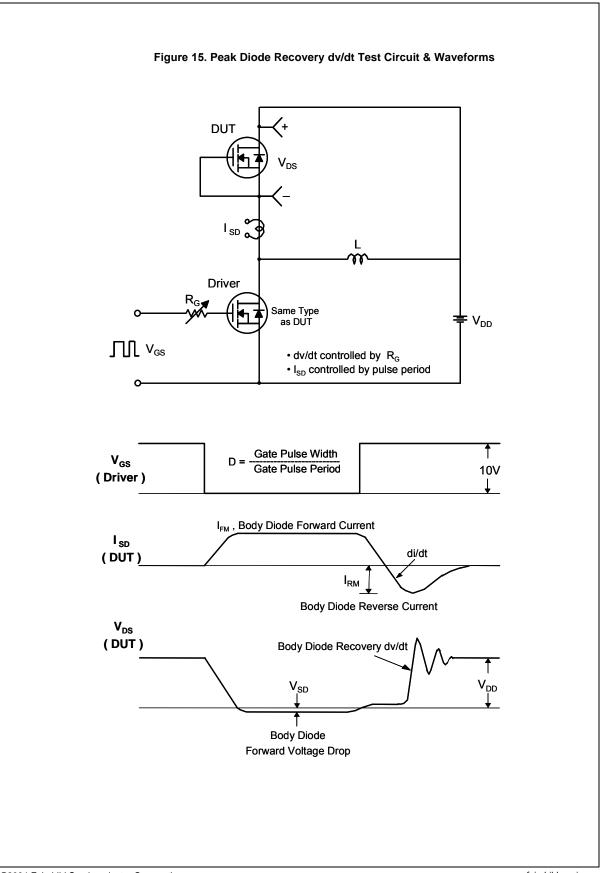
 $\textcircled{\sc c}2004$ Fairchild Semiconductor Corporation FQPF7N65C Rev. C1



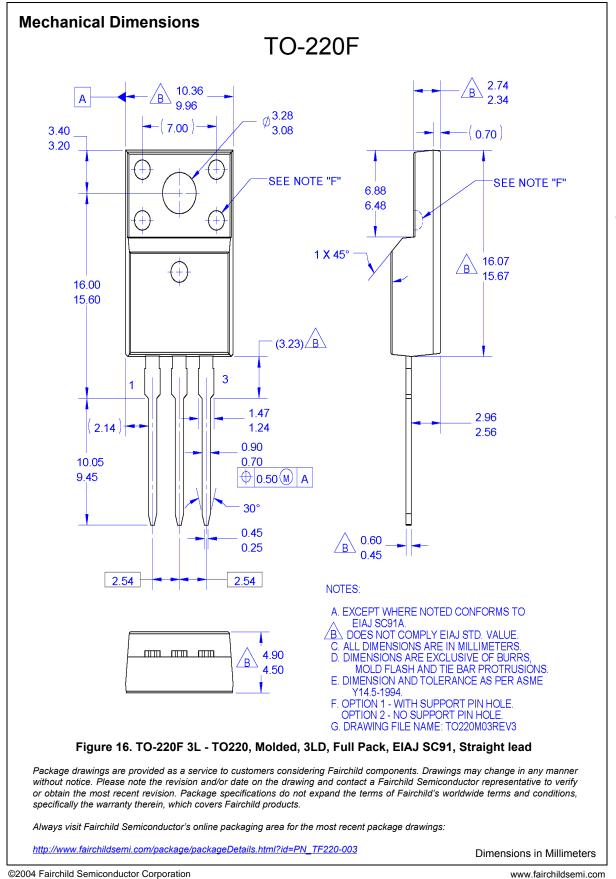
FQPF7N65C Rev. C1



©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1

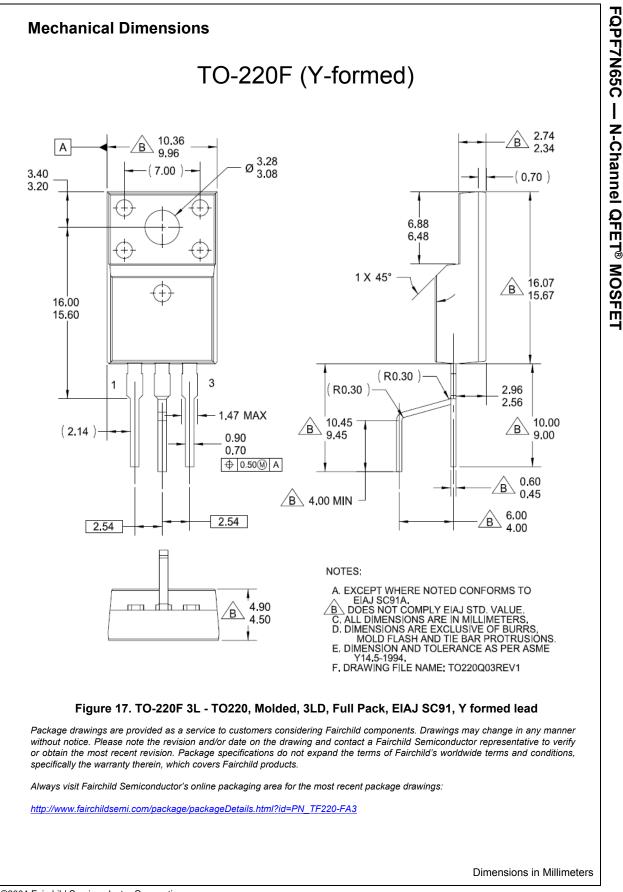


©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1



FQPF7N65C — N-Channel QFET[®] MOSFET

FQPF7N65C Rev. C1



©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1



SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

 $(1)_{\mathbb{R}}$

PowerTrench[®]

$\begin{array}{l} 2\text{Cool}^{\text{TM}} \\ \text{AccuPower}^{\text{TM}} \\ \text{AX-CAP}^{\otimes_*} \\ \text{BitSiC}^{\text{TM}} \\ \text{Build it Now}^{\text{TM}} \\ \text{CorePLUS}^{\text{TM}} \\ \text{CorePOWER}^{\text{TM}} \\ \text{CorePOWER}^{\text{TM}} \\ \text{CROSSVOLT}^{\text{TM}} \\ \text{CTL}^{\text{TM}} \\ \text{CUrrent Transfer Logic}^{\text{TM}} \\ \text{DEUXPEED}^{\otimes} \\ \text{Dual Cool}^{\text{TM}} \\ \text{EcoSPARK}^{\otimes} \\ \text{EfficientWax}^{\text{TM}} \end{array}$
EcoSPARK [®] EfficentMax™ ESBC™

Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT® FAST® FastvCore™ FETBench™

F-PFS™ FRFET® Global Power ResourceSM Green Bridge™ Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX[™] **ISOPLANAR™** Marking Small Speakers Sound Louder and Better™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ mWSaver™ OptoHiT™ OPTOLOGIC[®] **OPTOPLANAR®**

FPS™

PowerXS™ Programmable Active Droop™ QFĔT QS™ Quiet Series™ RapidConfigure™ тм Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START Solutions for Your Success™ SPM[®] STEALTH™ SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS[®] SyncFET™

Sync-Lock™ SYSTEM^{®*} GENERAL TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC[®] TriFault Detect™ TRUECURRENT®* μSerDes™ $\mathcal{N}_{\scriptscriptstyle{\mathsf{Ser}}}$ UHC® Ultra FRFET™

QPF7N65C — N-Channel QFET[®] MOSFET

UniFET™ VCX™ VisualMax™ VoltagePlus[™] XS™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support. Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their

parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS **Definition of Terms**

Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed Full Production		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete Not In Production		Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

©2004 Fairchild Semiconductor Corporation FQPF7N65C Rev. C1

Rev I64

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Downloaded from Arrow.com.